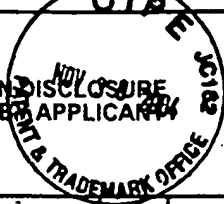



INFORMATION DISCLOSURE STATEMENT BY APPLICANT 		Application Number	10/664,659		
		Filing Date	September 17, 2003		
		First Named Inventor	T. MARUYAMA		
		Group Art Unit	2818		
		Examiner Name	THINH T. NGUYEN		
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TTN		JONES, K. A., et al., "Accurately determining the composition and thickness of layers in a GaAs/InGaAs superlattice." Appl. Phys. 76 (3), August 1, 1994, Pages 1609-1616.			
TTN		MAIER, M., et al., "Composition analysis of molecular beam epitaxy grown In _y Ga _{1-y} As/GaAs/Al _x Ga _{1-x} As quantum wells by determination of film thickness." J. Appl. Phys. 73 (8), April 15, 1993, 0021-8979/93/083820-07, American Institute of Physics, Pages 3820-3826.			
TTN		PAVESI, L. et al., "Photoluminescence of Al _x Ga _{1-x} As alloys." J. Appl. Phys. 75 (10), 0021-8979/94/75(10)4779/64, May 15, 1994			
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